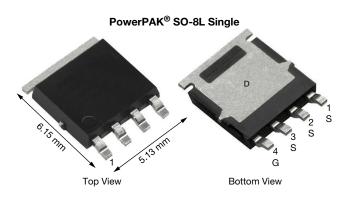
SQJ459EP



Vishay Siliconix

Automotive P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V _{DS} (V)	-60
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 V$	0.018
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 V$	0.024
I _D (A)	-52
Configuration	Single
Package	PowerPAK SO-8L

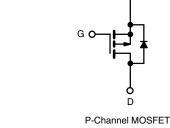


FEATURES

- TrenchFET[®] power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified ^c
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



KOHS COMPLIANT HALOGEN FREE



ABSOLUE MAXIMUM RATINGS	$(T_C = 25 \ ^\circ C, \text{ unless c})$	otherwise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V _{GS}	± 20	v	
Continuous Drain Current	T _C = 25 °C		-52		
Continuous Drain Current	T _C = 125 °C	I _D	-30		
Continuous Source Current (Diode Conduction)		I _S	-75	А	
Pulsed Drain Current ^a		I _{DM}	-200		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	-40		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	80	mJ	
Maximum Dawer Dissinction 8	T _C = 25 °C	P	83	W	
Maximum Power Dissipation ^a	T _C = 125 °C	P _D	27	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	° 0	
Soldering Recommendations (Peak Temperature) ^{d, e}			260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^b	R _{thJA}	65	°C/W
Junction-to-Case (Drain)		R _{thJC}	1.8	0/10

Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. When mounted on 1" square PCB (FR4 material).

c. Parametric verification ongoing.

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

S15-2327-Rev. A, 05-Oct-15

1

www.vishay.com

SQJ459EP Vishay Siliconix

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static	-						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = -250 \ \mu A$		-60	-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V_{GS} , I_D = -250 μ A	-1.5	-2.0	-2.5	v
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -60 V	I	-	-1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = -60 V, T _J = 125 °C	-	-	-50	μA
		$V_{GS} = 0 V$	V_{DS} = -60 V, T _J = 175 °C	-	-	-150	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = -10 V$	$V_{DS} \leq -5 V$	-30	-	-	Α
Drain-Source On-State Resistance ^a		$V_{GS} = -10 V$	I _D = -3.5 A	-	0.0155	0.0180	Ω
	В	$V_{GS} = -4.5 V$	I _D = -3.1 A	-	0.0206	0.0240	
	$V_{GS} = -10V$ $V_{GS} = -10V$	$V_{GS} = -10 V$	$I_D = -3.5 \text{ A}, \text{ T}_J = 125 \ ^\circ\text{C}$	-	0.0255	-	
		V _{GS} = -10 V	I _D = -3.5 A, T _J = 175 °C	-	0.0310	-	
Forward Transconductance b	9 _{fs}	V _{DS} =	-30 V, I _D = -15 A	-	40	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	3448	4586	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -30 V, f = 1 MHz	-	374	497	pF
Reverse Transfer Capacitance	C _{rss}			-	234	312	
Total Gate Charge ^c	Qg			-	73	108	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -40 \text{ V}, \text{ I}_{D} = -15 \text{ A}$	-	10	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	20	-	
Gate Resistance	R _g	f = 1 MHz		0.5	1.1	2	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	12	17	
Rise Time ^c	tr	$V_{DD} = -30 \text{ V}, \text{ R}_{\text{L}} = 30 \Omega$ $\text{I}_{\text{D}} \cong -1 \text{ A}, \text{ V}_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{g}} = 6 \Omega$		-	19	26	- ns
Turn-Off Delay Time ^c	t _{d(off)}			-	88	117	
Fall Time ^c	t _f			-	45	60	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	-200	Α
Forward Voltage	V _{SD}	c -	: -2.5 A, V _{GS} = 0	-	-0.8	-1.2	V

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

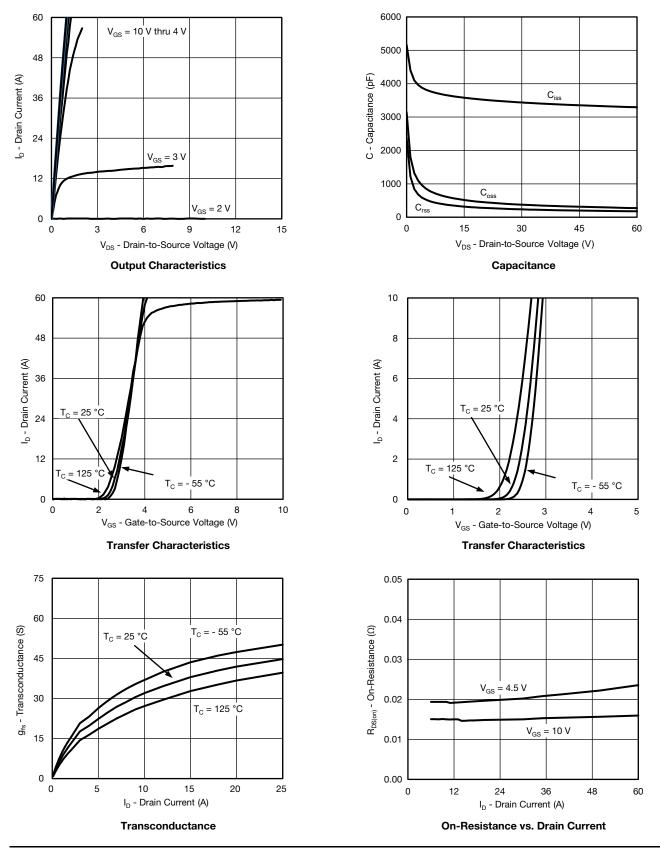
2



SQJ459EP

Vishay Siliconix

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S15-2327-Rev. A, 05-Oct-15

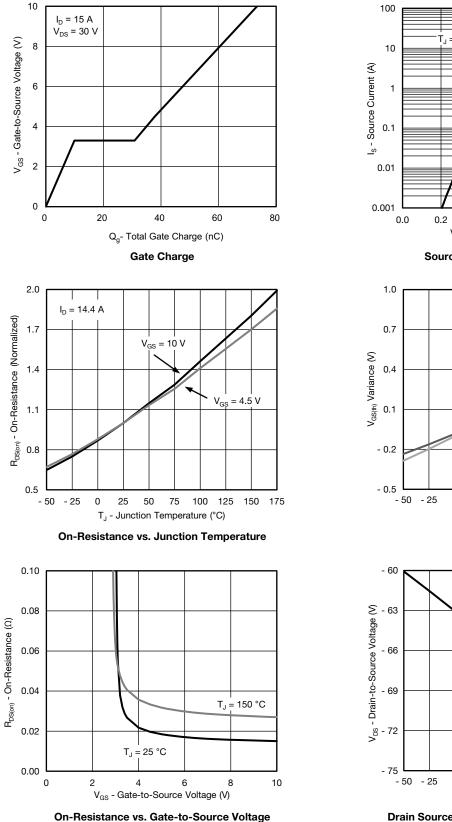
3

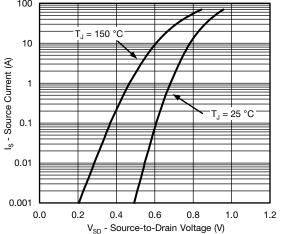
Document Number: 66963

For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

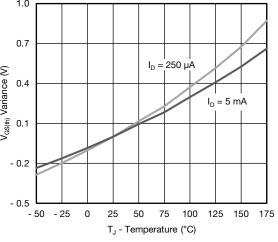


TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

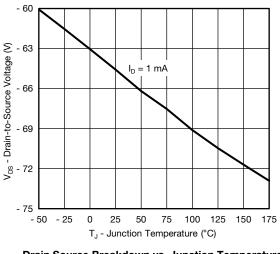




Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature

S15-2327-Rev. A, 05-Oct-15

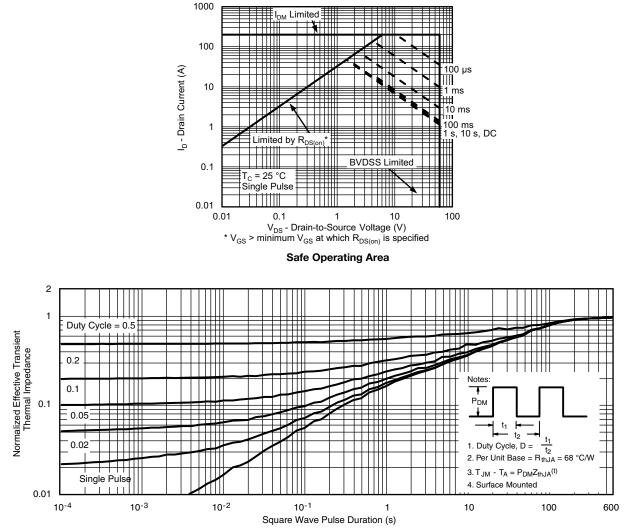
4

Document Number: 66963

For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



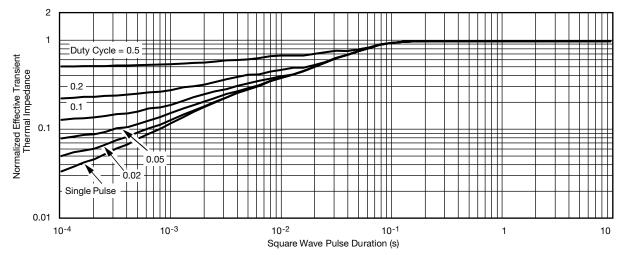
Normalized Thermal Transient Impedance, Junction-to-Ambient



SQJ459EP

Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

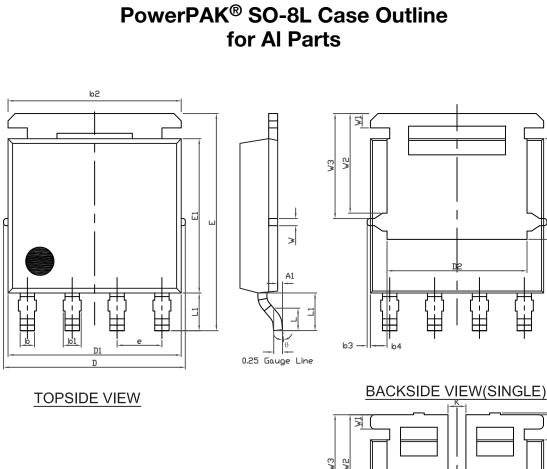
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?66963.

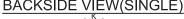


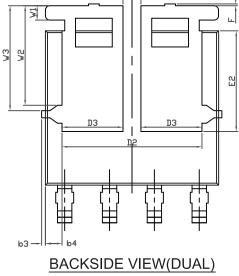
Ы





Revision: 07-Sep-15





1

Package Information



Vishay Siliconix

DIM		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094	•		0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC	•	0.050 BSC				
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
К		0.51			0.020			
W		0.23			0.009			
W1	0.41			0.016				
W2	2.82		0.111					
W3		2.96		0.117				
q	0°	-	10°	0°	-	10°		

Note

• Millimeters will gover



RECOMMENDED MINIMUM PAD FOR PowerPAK[®] SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)

Revision: 07-Feb-12



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay: SQJ459EP-T1_GE3